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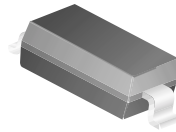
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MMSD914

Small Signal Diode



SOD123
COLOR BAND DENOTES CATHODE
TOP MARKING: 5D

Absolute Maximum Ratings * $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0	A
		2.0	A
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	400	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	312	$^\circ\text{C/W}$

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
V_R	Breakdown Voltage	$I_R = 5.0\mu\text{A}$	75		V
		$I_R = 100\mu\text{A}$	100		V
V_F	Forward Voltage	$I_F = 10\text{mA}$		1.0	V
I_R	Reverse Leakage	$V_R = 20\text{V}$		25	nA
		$V_R = 20\text{V}, T_A = 150^\circ\text{C}$		50	μA
		$V_R = 75\text{V}$		5.0	μA
C_T	Total Capacitance	$V_R = 0\text{V}, f = 1.0\text{MHz}$		4.0	pF
t_{rr}	Reverse Recovery Time	$I_F = 10\text{mA}, V_R = 6.0\text{V}, I_{RR} = 1.0\text{mA}, R_L = 100\Omega$		4.0	ns
$V_{F(\text{peak})}$	Peak Forward Recovery Voltage	$I_F = 50\text{mA}$, Peak square wave pulse width = 0.1 μs , 5kHz - 100kHz rep rate		2.5	V

Typical Characteristics

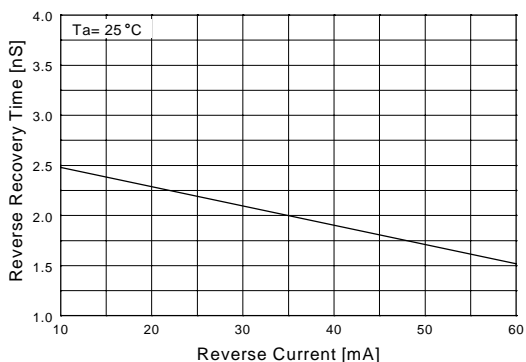


Figure 7. Reverse Recovery Time vs Reverse Current
TRR - IR 10 mA vs 60 mA

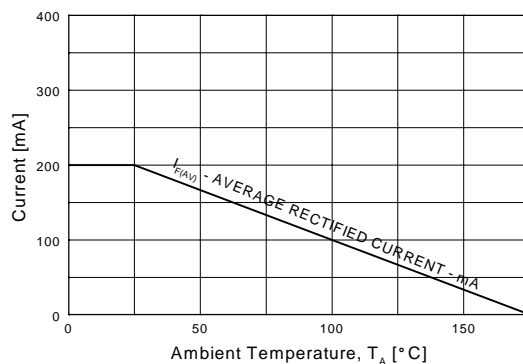


Figure 8. Average Rectified Current ($I_{F(AV)}$) versus Ambient Temperature (T_a)

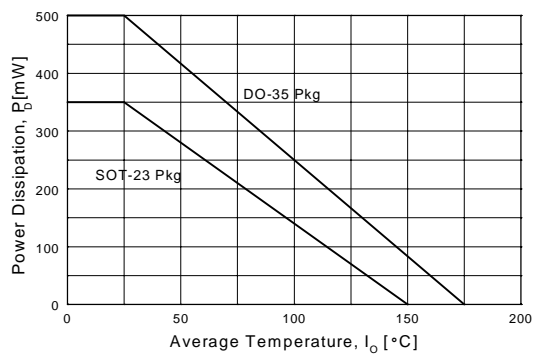


Figure 9. Power Derating Curve

Typical Characteristics

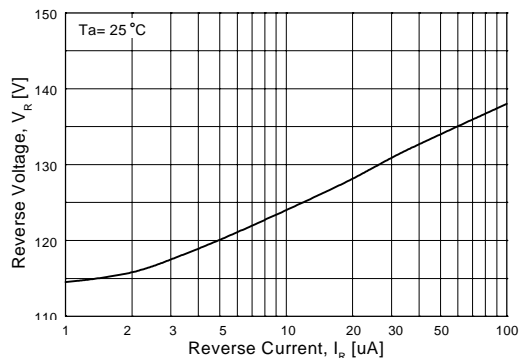


Figure 1. Reverse Voltage vs Reverse Current
BV - 1.0 to 100uA

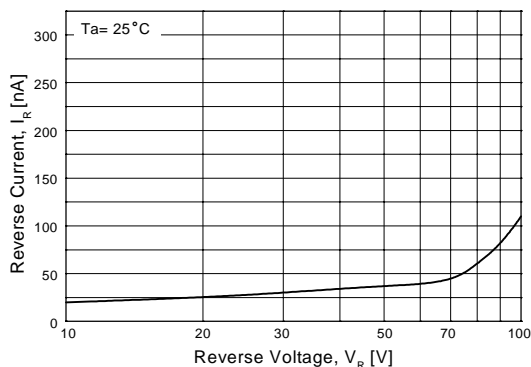


Figure 2. Reverse Current vs Reverse Voltage
IR - 10 to 100 V

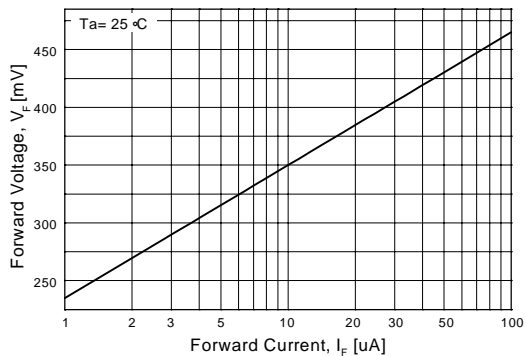


Figure 3. Forward Voltage vs Forward Current
VF - 1.0 to 100 uA

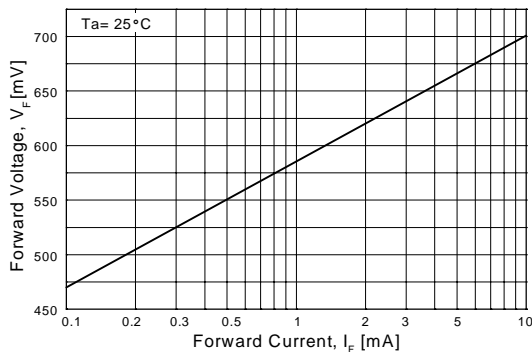


Figure 4. Forward Voltage vs Forward Current
VF - 0.1 to 10 mA

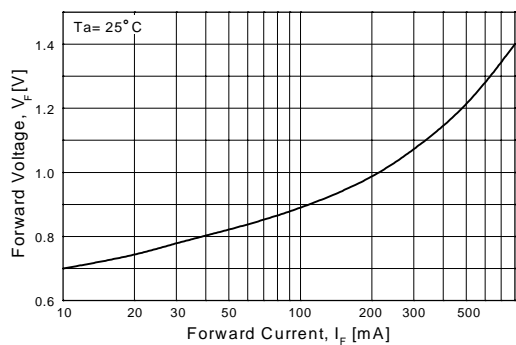


Figure 5. Forward Voltage vs Forward Current
VF - 10 - 800 mA

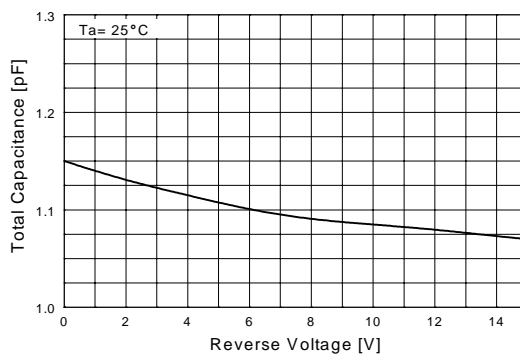


Figure 6. Total Capacitance vs Reverse Voltage

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